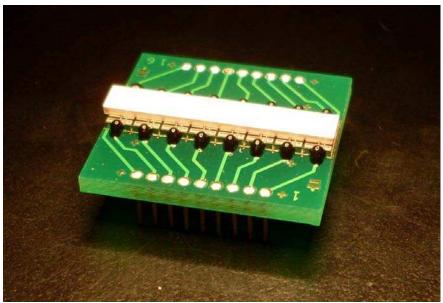
# **Photodiode Arrays (PDA)**



The VTA1216H-L-SC-08-1 is well-suited to X-ray Security Scanning at airports and at critical infrastructure locations

The VTA1216H series is a 16-channel High Resolution Photodiode Array (PDA). There are 8 dual-element photodiodes mounted directly on an FR-4 PCB. Wire bonds from the top of the chip are bonded directly to gold bond pads on the PCB. The pitch (sensor-to-sensor spacing of adjacent chips) for this series is 1.2 mm; other pitches are available as off the shelf or as custom devices.

A transparent coating material covers the photo-sensitive chip area while a globtop encapsulant protects the bond wires from damage. These parts are available with or without a scintillator material mounted over the photodiode active area to convert X-rays into visible photons of light.

These devices can be used as single energy detectors with a range of available scintillator crystals. They can also be used in dual-energy systems in a stacked configuration for simultaneous detection of low and high energy radiation for better atomic number discrimination. This technique is particularly useful in security applications such as luggage scanning in airports or at critical infrastructure locations (e.g. train stations, sports stadiums, courthouses).

#### **Key Features**

- Photodiode with extremely low dark current
- High signal-to-noise ratio
- Scintillator crystals available on demand to convert incident X-rays into visible photons
- 16-channels at 1.2 mm pitch

#### **Applications**

- Luggage Scanning
- Food inspection
- Cargo/container screening
- Nondestructive testing
- Industrial inspection



## **Photodiode Arrays (PDA)**

### **Nomenclature**

VTA1216H series part numbers are in the following format: VTA1216H-W-XX-YY-Z

W: Energy type (H-High, L-Low)

**XX**: Scintillator (NC-No scintillator, SC-With scintillator)

YY: Scintillator type (see Scintillator Selection Guide section below for all standard scintillator types)

**Z:** Photodiode type (0-Regular capacitance, 1-Low capacitance)

### Scintillator Selection Guide\*

Hig	h Energy Scintillator	Low Energy Scintillator			
Type no.	Characteristics	Type no.	Characteristics		
VTA1216H-H-NC-00	No scintillator	VTA1216H-L-NC-00	No scintillator		
VTA1216H-H-SC-01	CsI-TI, 3 mm thick, segmented	VTA1216H-L-SC-03	Gd <sub>2</sub> O <sub>2</sub> S:Tb sheet, 310 μm thick, DRZ-High		
VTA1216H-H-SC-05	Gd <sub>2</sub> O <sub>2</sub> S:Pr, 1.5 mm thick, segmented	VTA1216H-L-SC-08	$Gd_2O_2S$ :Prsheet, 200 $\mu$ m thick		

<sup>\*</sup> Scintillators are available using other materials and geometries upon request.

### **Typical Scintillator Characteristics\***

Parameter	SC-01	SC-05	SC-03	SC-08	Unit
Composition	CsI-Tl	Gd₂O₂S:Pr	Gd₂O₂S:Tb sheet	Gd <sub>2</sub> O <sub>2</sub> S:Pr sheet	
Emission peak	550	512	545	512	nm
Decay time (@ 1/e)	1	4	600	3	μs
Decay time to 10% peak	5	7	1500	7	μs
Afterglow	0.500 (after 20ms)	0.015 (after 100ms)	-	0.020 (after 100ms)	%
Density	4.51	7.33	7.33	7.33	gm/cm <sup>3</sup>

<sup>\*</sup> These characteristics are typical, specifications will vary from manufacturer.

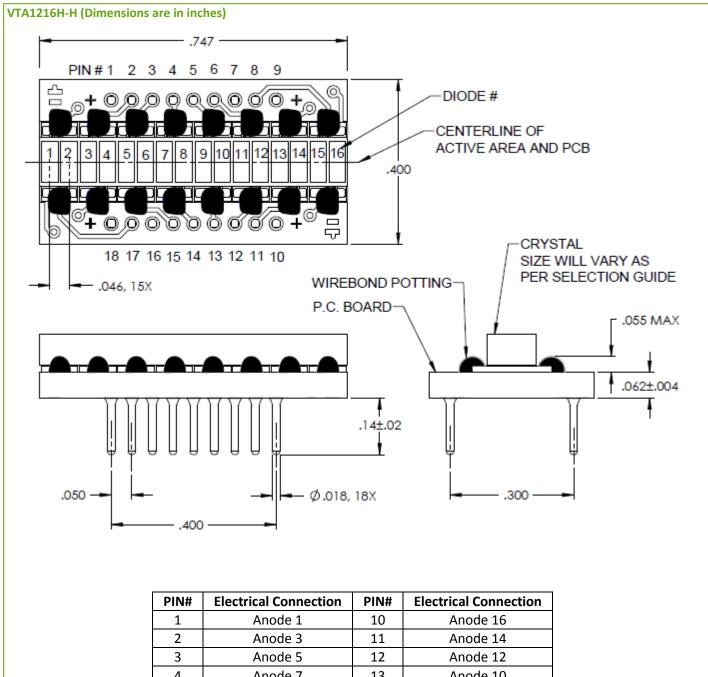
# **Photodiode Arrays (PDA)**

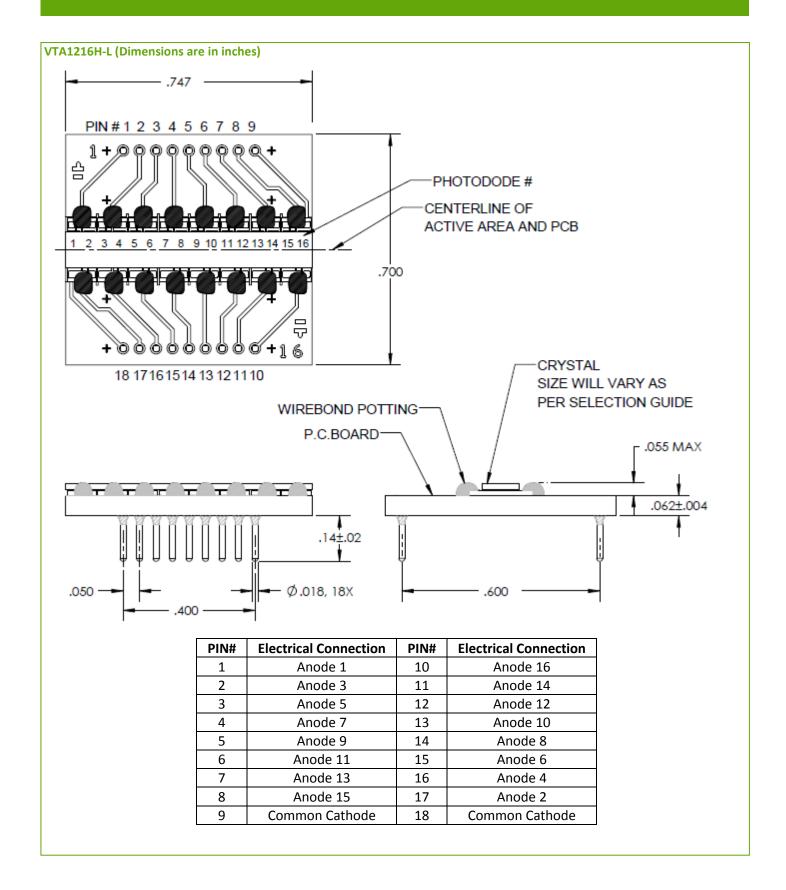
### **Electro-Optical Characteristics**

Treet o Optical Characteristics		VTA1216H-W-XX-YY-0		VTA1216H-W-XX-YY-1					
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Short circuit current	I <sub>sc</sub>	25° C / 1000lx 2850 K	10	13	16	10	13	16	μΑ
Open circuit voltage	V <sub>oc</sub>	25° C / 1000lx 2850 K	380			380			mV
Forward voltage	V <sub>F</sub>	25° C / 1 mA	400		700	400		700	mV
Dark current	I <sub>D</sub>	25° C/ 0 lx ±10 mV applied		2	30		15	50	pA
Junction capacitance	C <sub>J</sub>	25° C / 0 lx 0 V applied		200	300		25	35	pF
Breakdown voltage	$V_{BR}$	25° C / 0 lx	20			20			V
Responsivity @ 550 nm	λ <sub>550</sub>	25° C ± 10 mV applied	0.26	0.32		0.26	0.32		A/W
Responsivity @ 950 nm	λ <sub>950</sub>	25° C ± 10 mV applied	0.45	0.55		0.45	0.55		A/W
Peak spectral sensitivity	$\lambda_{max}$			900			900		nm
Spectral response	$\lambda_{range}$		400		1100	400		1100	nm
Effective sensitive area (per element)	А		1.72		2.00			mm²	
Chip size (dual-element type)	l*w		4.90 x 2.25		4.58 x 2.25			mm²	
Element pitch			1.18		1.18			mm	
Number of elements			16		16			element	

### **Photodiode Arrays (PDA)**

### **Physical Configuration**





### **Photodiode Arrays (PDA)**

#### **About Excelitas Technologies**

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